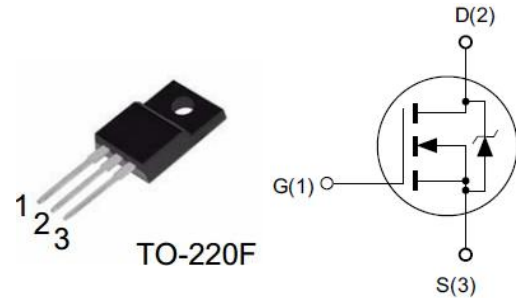


Features

- ◆ 650V, 30A, $R_{DS(ON)}(Typ.) = 105m\Omega @ V_{GS} = 10V$
- ◆ Advanced Super Junction Technology
- ◆ Easy To Control Gate Switching
- ◆ 100% Avalanche Tested

Application

- ◆ Server power and Telecom power
- ◆ EV Charging, Solar inverter and UPS Application
- ◆ Boost PFC switch, Half bridge or Asymmetric half bridge
- ◆ Series resonance half bridge and full bridge topologies



Absolute Maximum Ratings $T_c = 25^\circ C$ unless otherwise noted

Symbol	Parameter	Rating	Unit
V_{DS}	Drain-Source Voltage ^a	650	V
V_{GS}	Gate-Source Voltage	± 30	
I_D	Drain Current-Continuous, $T_c = 25^\circ C$	30	A
I_{DM}	Drain Current-Pulsed ^b	90	
P_D	Maximum Power Dissipation, $T_c = 25^\circ C$	36.7	W
dv/dt	Peak Diode Recovery dv/dt ^c	50	V/ns
E_{AS}	Single Pulsed Avalanche Energy ^d	1140	mJ
T_J, T_{STG}	Operating and Store Temperature Range	150, -55 to 150	$^\circ C$

Thermal Characteristics

Symbol	Parameter	Value	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case	3.4	$^\circ C/W$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	62	

Electrical Characteristics $T_J = 25^\circ C$ unless otherwise noted

■ Off Characteristics

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$	650	-	-	V
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 650V, V_{GS} = 0V$	-	-	2	μA
I_{GSS}	Forward Gate Body Leakage Current	$V_{DS} = 0V, V_{GS} = 30V$	-	-	100	nA

■ On Characteristics

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250\mu A$	3.0	-	5.0	V
$R_{DS(on)}$	Static Drain-Source On-Resistance ^c	$V_{GS} = 10V, I_D = 15A$	-	105	120	mΩ

■ Dynamic Characteristics

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
R_G	Gate Resistance	$f = 1.0MHz$	-	12.6	-	Ω
C_{iss}	Input Capacitance	$V_{DS} = 100V,$ $V_{GS} = 0V,$ $f = 1.0MHz$	-	2566	-	pF
C_{oss}	Output Capacitance		-	90.8	-	
C_{rss}	Reverse Transfer Capacitance		-	1.8	-	

■ On Characteristics

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
$t_{d(on)}$	Turn-On Delay Time	$V_{DD} = 400V,$ $V_{GS} = 10V,$ $I_D = 19A,$ $R_G = 2\Omega$	-	32	-	ns
t_r	Turn-On Rise Time		-	62	-	
$t_{d(off)}$	Turn-Off Delay Time		-	100	-	
t_f	Turn-Off Fall Time		-	59	-	
Q_g	Total Gate Charge	$V_{DD} = 400V,$ $V_{GS} = 0 \text{ to } 10V,$ $I_D = 19A$	-	58.3	-	nC
Q_{gs}	Gate-Source Charge		-	18.8	-	
Q_{gd}	Gate-Drain Charge		-	20.6	-	

■ Drain-Source Diode Characteristics

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
V_{SD}	Drain-Source Diode Forward Voltage	$V_{GS} = 0V, I_F = 1A$	-	0.67	-	V
T_{rr}	Body Diode Reverse Recovery Time	$V_R = 400V, I_F = 17A$ $di_F/dt = 100A/\mu s$	-	128.8	-	ns
Q_{rr}	Body Diode Reverse Recovery Charge	$V_R = 400V, I_F = 17A$ $di/dt = 100A/\mu s$	-	0.821	-	μC
I_{rrm}	Peak reverse recovery current	$V_R = 400V, I_F = 17A$ $di/dt = 100A/\mu s$	-	12.06	-	A

Notes:

- $T_J = +25^\circ C$ to $+150^\circ C$.
- Repetitive rating: pulse width limited by maximum junction temperature.
- Pulse width $\leq 300\mu s$; duty cycle $\leq 2\%$.
- $L = 10mH, V_{DD} = 100V, I_{AS} = 15.1A, R_G = 25\Omega$ Starting $T_J = 25^\circ C$.

■ Characteristic Curve

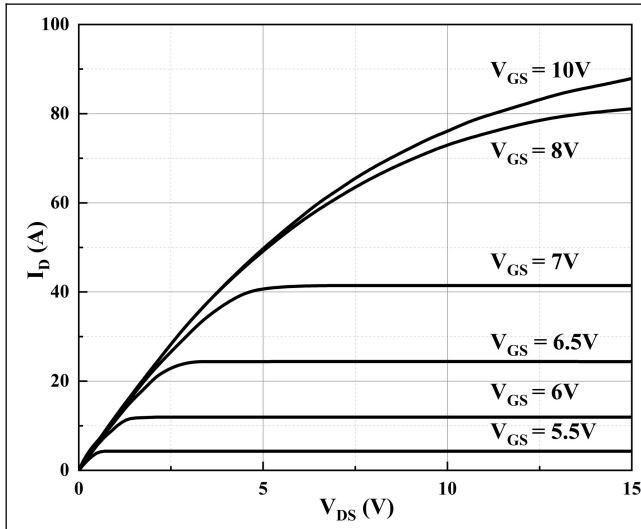


Figure 1. Typical Output Characteristics

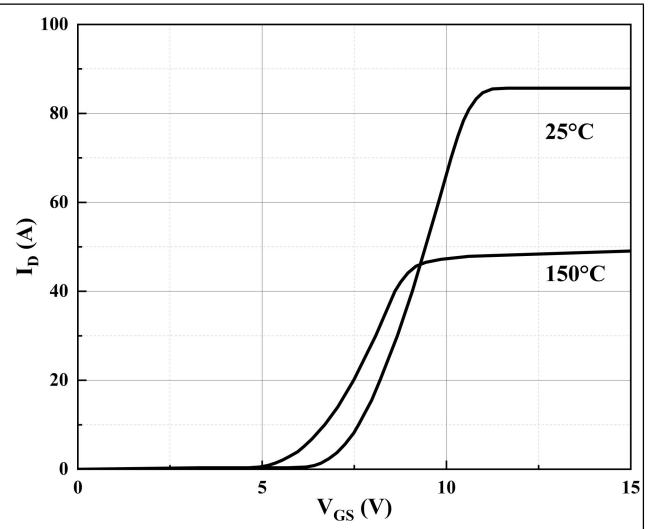


Figure 2. Typical Transfer Characteristics

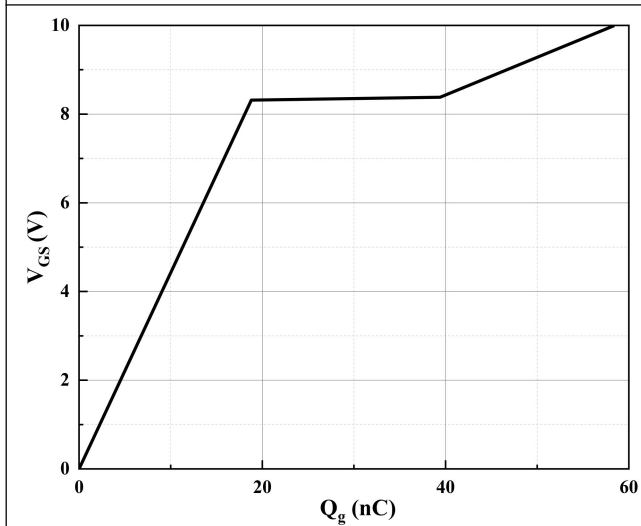


Figure 3. Typical Gate Charge

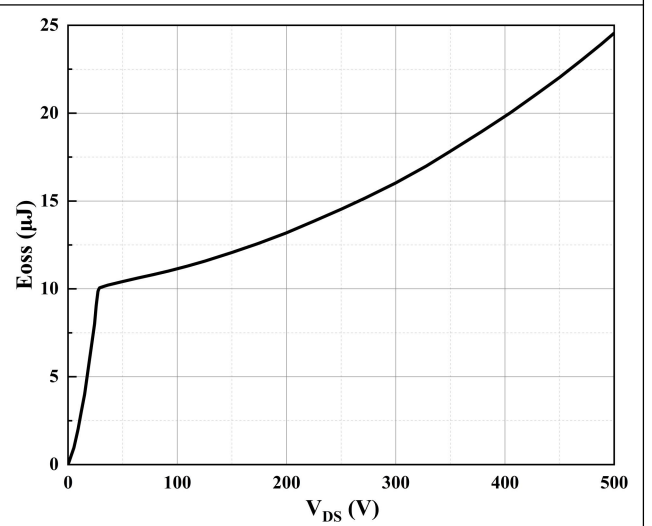


Figure 4. Typical C_{oss} Stored Energy

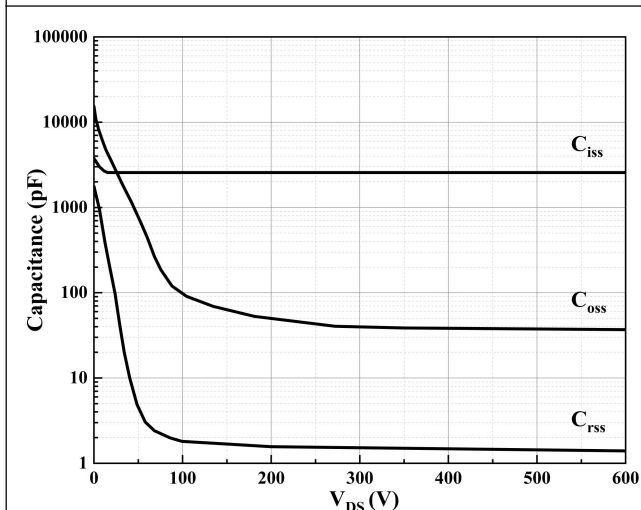


Figure 5. Typical Capacitance

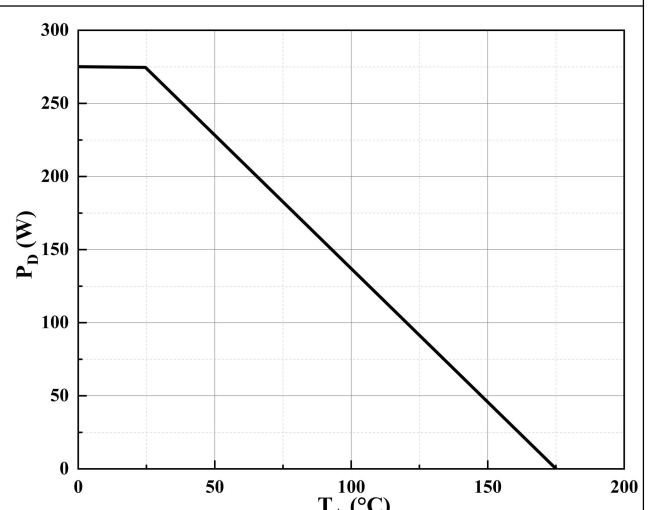


Figure 6. Typical Power Dissipation

■ Characteristic Curve

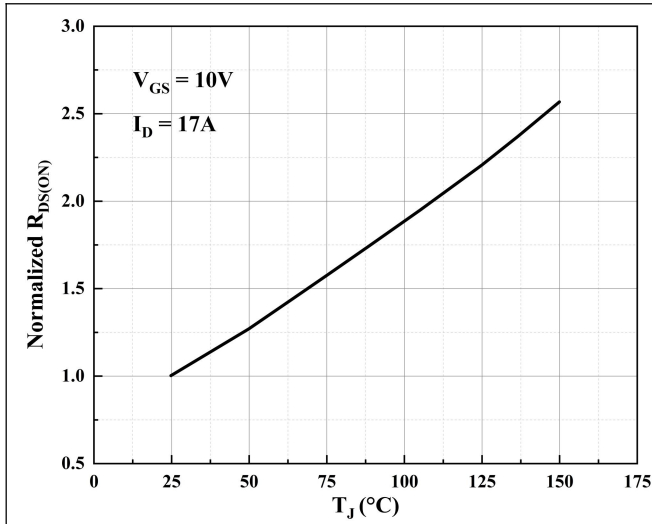


Figure 7. Typical On-Resistance vs. Junction Temperature

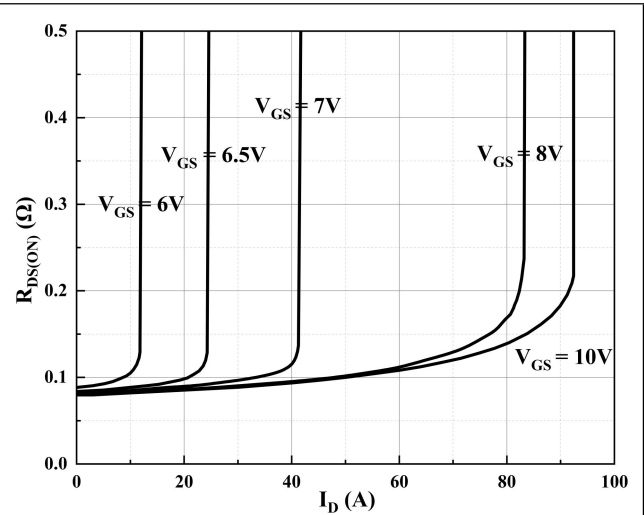


Figure 8. Typical Drain-source On-state Resistance

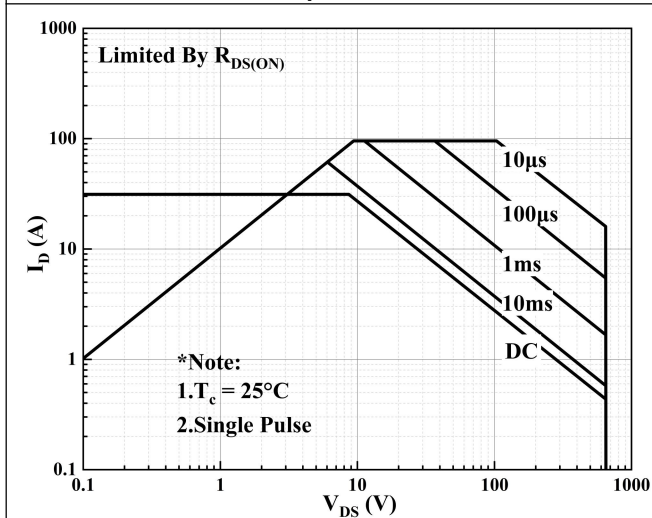


Figure 9. Maximum Safe Operating Area

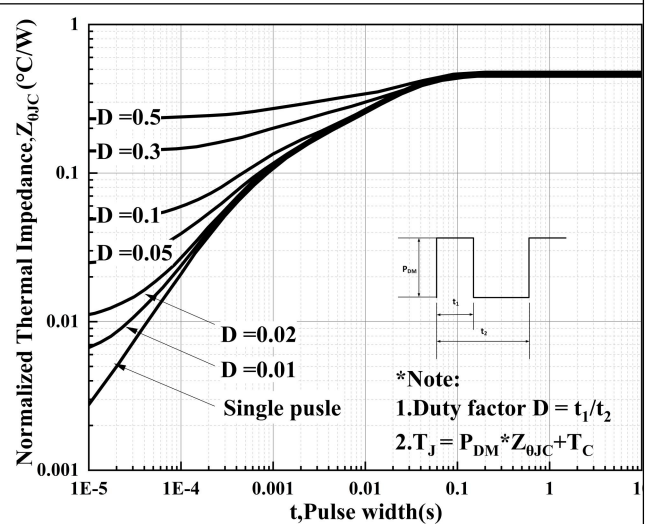


Figure 10. Maximum transient thermal impedance

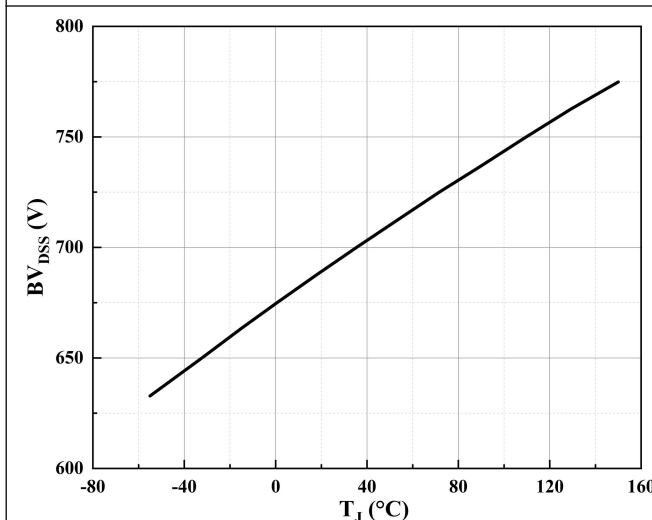


Figure 11. Drain-Source Breakdown Voltage

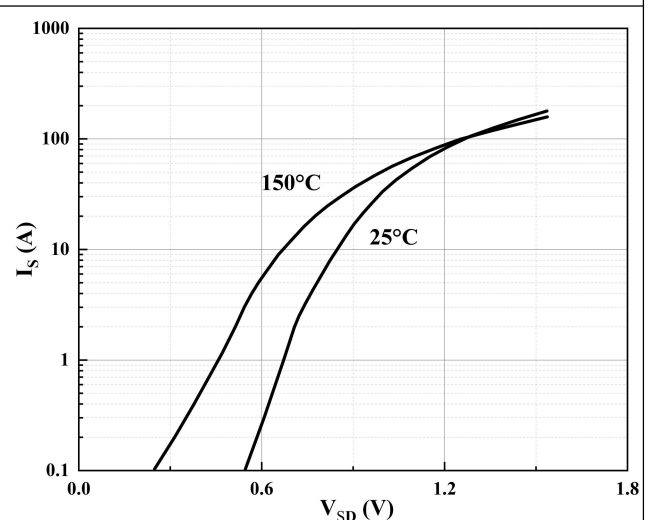


Figure 12. Forward characteristics of reverse diode



Technical drawing of a mechanical part, showing three views: top, front, and side. The drawing includes dimensions and tolerances.

Top View:

- Overall width: 10.16 ± 0.2
- Overall height: 15.87 ± 0.2
- Central circular hole: $\varnothing 3.18$
- Four corner holes: $\varnothing 1.5 \times 0.1 \pm 0.05 \text{ DP}$
- Distance from center to corner holes: 2.54

Front View:

- Overall height: 12.93 ± 0.2
- Distance from top edge to center of corner holes: 1.20
- Distance from center of corner holes to bottom edge: 1.27 ± 0.05
- Distance from center of corner holes to center of central hole: 0.80

Side View:

- Overall width: 4.70 ± 0.05
- Distance from top edge to center of corner holes: 2.54
- Distance from center of corner holes to bottom edge: 6.68 ± 0.2
- Distance from center of corner holes to center of central hole: 2.76 ± 0.03
- Distance from center of central hole to bottom edge: 0.50